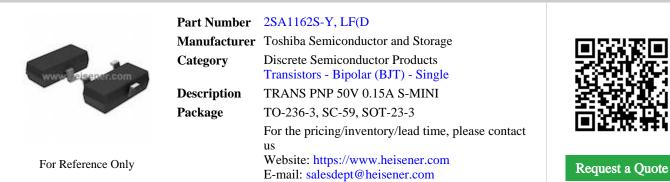


## 2SA1162S-Y, LF(D

#### 2SA1162S-Y, LF(D Information



#### **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



#### 2SA1162S-Y, LF(D Specifications

	2SA1162S-Y, LF(D
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	PNP
Current - Collector (Ic) (Max)	150mA
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	300mV @ 10mA, 100mA
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	120 @ 2mA, 6V
Power - Max	150mW
Frequency - Transition	80MHz
Operating Temperature	125°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	S-Mini
	Report errors?

#### 2SA1162S-Y, LF(D Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE EUARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### 2SA1162S-Y, LF(D Payment Methods



### 2SA1162S-Y, LF(D Shipping Methods



If you have any question about 2SA1162S-Y, LF(D, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com